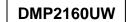


NOT RECOMMENDED FOR NEW DESIGN **USE DMP2165UW**





March 2018

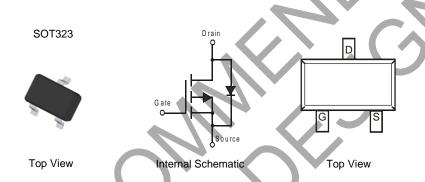
P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- $100m\Omega @ V_{GS} = -4.5V$
- $120m\Omega$ @ $V_{GS} = -2.5V$
- $160m\Omega @ V_{GS} = -1.8V$
- Very Low Gate Threshold Voltage V_{GS(TH)} ≤ 1V
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMP2160UWQ)

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.006 grams (Approximate)



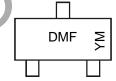
Ordering Information (Note 4)

| | | _ | | |
|-------------|------------|---|--------|------------------|
| Part Number | Compliance | | Case | Packaging |
| DMP2160UW-7 | Standard | | SOT323 | 3000/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DMF = Marking Code YM = Date Code Marking Y = Year (ex: F = 2018)M = Month (ex: 9 = September)

Data Coda Kay

| Date Code Rey | | | | | | | | | | | | |
|---------------|------|-----|------|------|-----|------|------|-----|------|------|-----|------|
| Year | 2018 | | 2019 | 2020 | | 2021 | 2022 | | 2023 | 2024 | | 2025 |
| Code | F | | G | Н | | I | J | | K | L | | M |
| | | | | | | | | | | | | |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| | | | | | | | | | | | N | _ |



NOT RECOMMENDED FOR NEW DESIGN USE DMP2165UW

DMP2160UW

| Characteristic | | Symbol | Value | Unit |
|------------------------|--|------------------|--------------|------|
| Drain-Source Voltage | | V _{DSS} | -20 | V |
| Gate-Source Voltage | | V _{GSS} | ±12 | V |
| Drain Current (Note 5) | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | I _D | -1.5 -1.2 | А |
| Pulsed Drain Current | | I _{DM} | -10 | Α |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|---|------------------|-------------|------|
| Total Power Dissipation (Note 5) | P_{D} | 350 | mW |
| Thermal Resistance, Junction to Ambient | $R_{	heta JA}$ | 360 | °C/W |
| Operating and Storage Temperature Range | T_{J}, T_{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

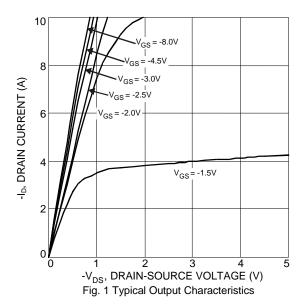
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | | |
|--|-------------------------|------|------|--------------|----------|---|--|--|
| OFF CHARACTERISTICS (Note 6) | | | 7 | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | | 1 | > | $V_{GS} = 0V, I_D = -250\mu A$ | | |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | 1 | 1 | -1.0 | μA | $V_{DS} = -20V, V_{GS} = 0V$ | | |
| Gate-Source Leakage | I _{GSS} | | 1 | ±100 ±800 | nA | $V_{GS} = \pm 8V, V_{DS} = 0V$ $V_{GS} = \pm 12V, V_{DS} = 0V$ | | |
| ON CHARACTERISTICS (Note 6) | | | | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | -0.4 | -0.6 | -0.9 | V | $V_{DS} = V_{GS}, I_D = -250 \mu A$ | | |
| | | | 75 | 100 | | $V_{GS} = -4.5V$, $I_D = -1.5A$ | | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | 1-1 | 90 | 120 | mΩ | $V_{GS} = -2.5V$, $I_D = -1.2A$ | | |
| | | | 120 | 160 | | $V_{GS} = -1.8V, I_D = -1A$ | | |
| Forward Transconductance | g FS | + | 4 | 1 | S | $V_{DS} = -10V$, $I_D = -1.5A$ | | |
| Diode Forward Voltage (Note 6) | V _{SD} | _ | - | -1.0 | V | $V_{GS} = 0V$, $I_{S} = -1.0A$ | | |
| DYNAMIC CHARACTERISTICS | DYNAMIC CHARACTERISTICS | | | | | | | |
| Input Capacitance | C _{iss} | _ | 627 | _ | pF | | | |
| Output Capacitance | Coss | _ | 64 | _ | pF | $V_{DS} = -10V, V_{GS} = 0V$ f = 1.0MHz | | |
| Reverse Transfer Capacitance | C _{rss} | _ | 53 | _ | pF | 1 - 1.01VII 12 | | |

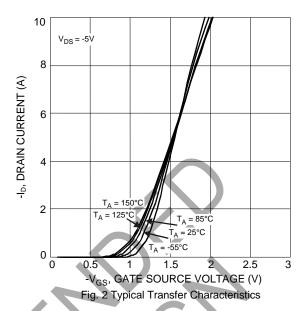
Notes: 5. Device mounted on 1inch² FR-4 PCB with 2 oz. Copper. t ≤ 10 sec. 6. Short duration pulse test used to minimize self-heating effect.

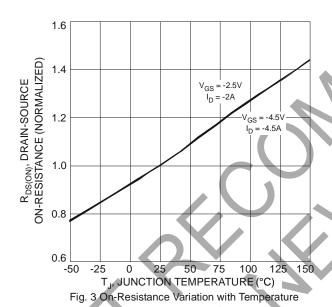


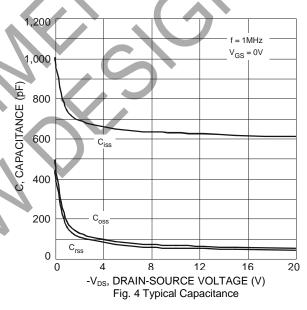
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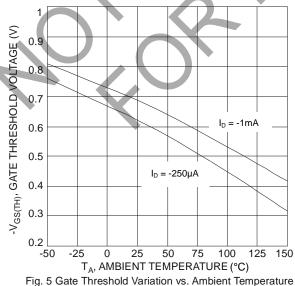
DMP2160UW

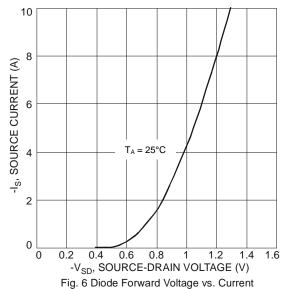




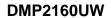














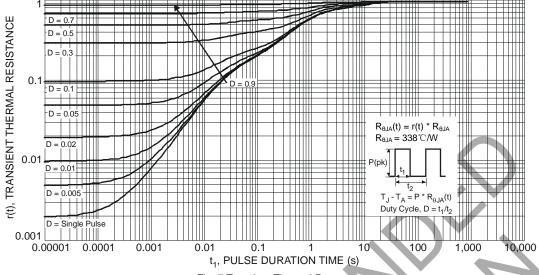


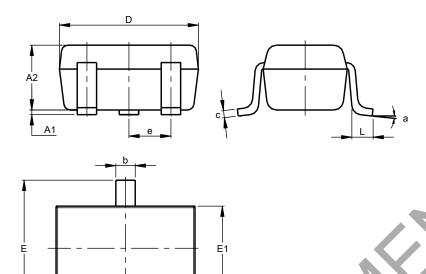
Fig. 7 Transient Thermal Response



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323

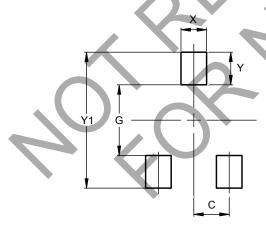


| SOT323 | | | | | | | | | |
|----------------|----------------------|---------|-------|--|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | | |
| A1 | 0.00 | 0.10 | 0.05 | | | | | | |
| A2 | 0.90 | 1.00 | 0.95 | | | | | | |
| b | 0.25 | 0.40 | 0.30 | | | | | | |
| С | 0.10 | 0.18 | 0.11 | | | | | | |
| D | 1.80 | 2.20 | 2.15 | | | | | | |
| Е | 2.00 | 2.20 | 2.10 | | | | | | |
| E1 1.15 | | 1.35 | 1.30 | | | | | | |
| е | C |).650 B | SC | | | | | | |
| e1 | 1.20 | 1.40 | 1.30 | | | | | | |
| F | 0.375 | 0.475 | 0.425 | | | | | | |
| L 0.25 | | 0.40 | 0.30 | | | | | | |
| а | 0° | 8° | | | | | | | |
| All | All Dimensions in mm | | | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323



| Dimensions | Value (in mm) |
|------------|------------------|
| C | 0.650 |
| G | 1.300 |
| X | 0.470 |
| Y | 0.600 |
| Y1 | 2.500 |



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DMP2160UW

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